## NSN 5962-01-329-7165

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view Online at https://aerobasegroup.com/nsn/5962-01-329-7165
Overall Height:
0.432 inches
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.172 inches and 0.217 inches
Maximum Power Dissipation Rating:
275.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Ultraviolet erasable and monolithic and programmable and w/enable and w/buffered output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
40.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
14.00 volts total supply
Capitance Rating Per Characteristic:
12.00 input picofarads and 14.00 output picofarads
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:

N/a

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Demilitarization:

No

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